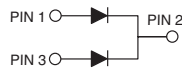
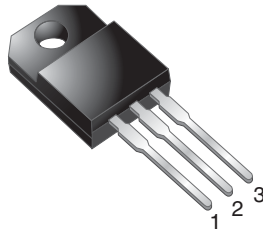


## Dual High Voltage Trench MOS Barrier Schottky Rectifier

**TMBS®**
**ITO-220AB**


### FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 5.0 A
$V_{RRM}$	90 V, 100 V
$I_{FSM}$	120 A
$V_F$	0.75 V
$T_J$ max.	150 °C
Package	ITO-220AB
Circuit configuration	Common cathode

### MECHANICAL DATA

**Case:** ITO-220AB

Molding compound meets UL 94 V-0 flammability rating  
 Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs max.

### MAXIMUM RATINGS ( $T_C = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	MBRF1090CT	MBRF10100CT	UNIT
Max. repetitive peak reverse voltage	$V_{RRM}$	90	100	V
Working peak reverse voltage	$V_{RWM}$	90	100	V
Max. DC blocking voltage	$V_{DC}$	90	100	V
Max. average forward rectified current at $T_C = 105\text{ °C}$	$I_{F(AV)}$	total device		A
		per diode		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	120		A
Non-repetitive avalanche energy at $T_J = 25\text{ °C}$ , $L = 60\text{ mH}$ per diode	$E_{AS}$	60		mJ
Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$ , 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$ per diode	$I_{RRM}$	0.5		A
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000		V/ $\mu\text{s}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-65 to +150		°C
Isolation voltage from terminal to heatsink with $t = 1\text{ min}$	$V_{AC}$	1500		V



ELECTRICAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	MBRF1090CT	MBRF10100CT	UNIT
Maximum instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 5.0 A	T <sub>C</sub> = 125 °C	V <sub>F</sub>	0.75		V
	I <sub>F</sub> = 5.0 A	T <sub>C</sub> = 25 °C		0.85		
Maximum reverse current per diode at working peak reverse voltage <sup>(2)</sup>			I <sub>R</sub>	100		μA
				6.0		mA

**Notes**

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	MBRF1090CT	MBRF10100CT	UNIT
Typical thermal resistance per diode	R <sub>θJC</sub>	6.8		°C/W

ORDERING INFORMATION (EXAMPLE)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	MBRF10100CT-M3/4W	1.75	4W	50/tube	Tube

### RATINGS AND CHARACTERISTICS CURVES (T<sub>C</sub> = 25 °C unless otherwise noted)

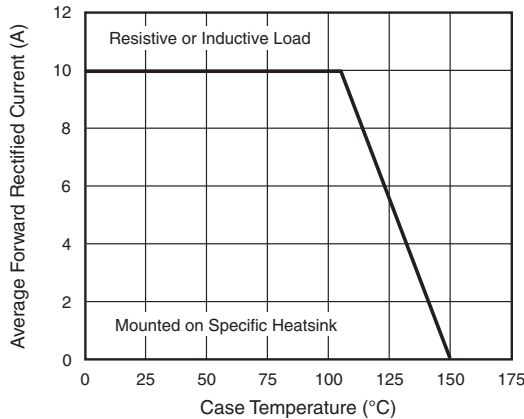


Fig. 1 - Forward Current Derating Curve

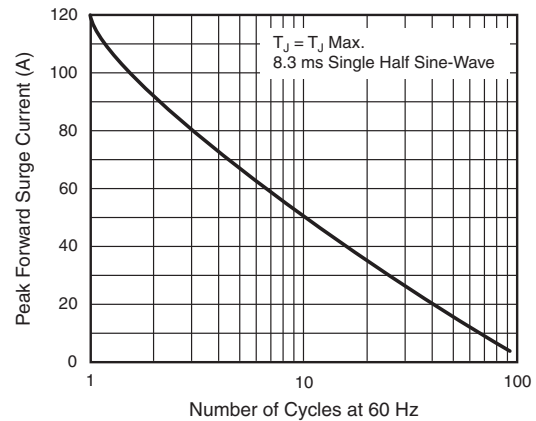


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

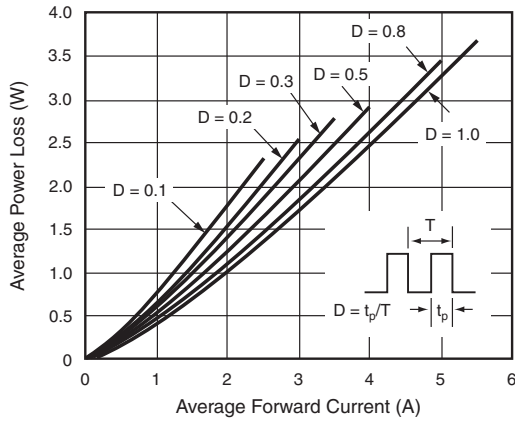


Fig. 3 - Forward Power Loss Characteristics Per Diode

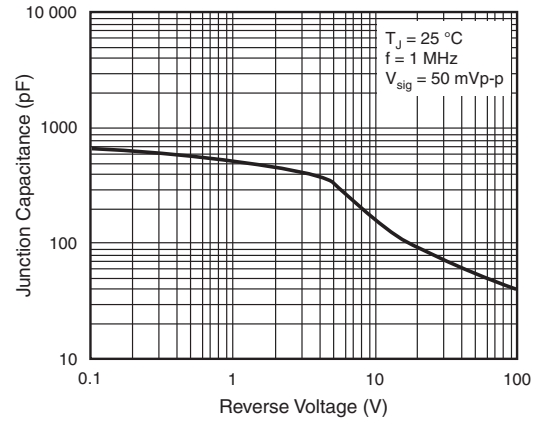


Fig. 6 - Typical Junction Capacitance Per Diode

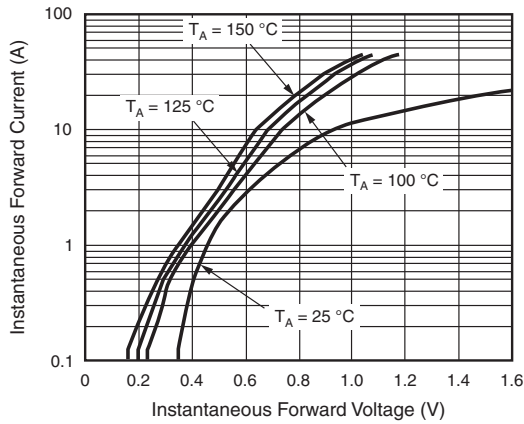


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

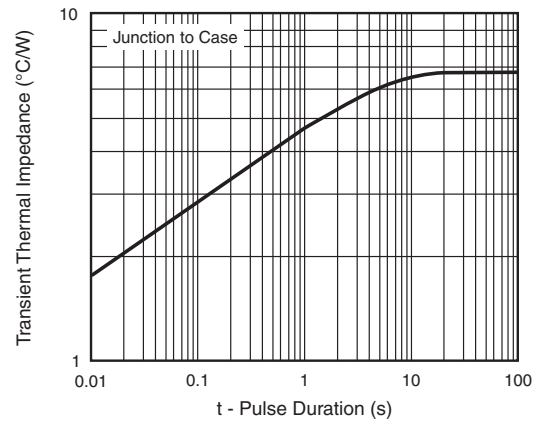


Fig. 7 - Typical Transient Thermal Impedance Per Diode

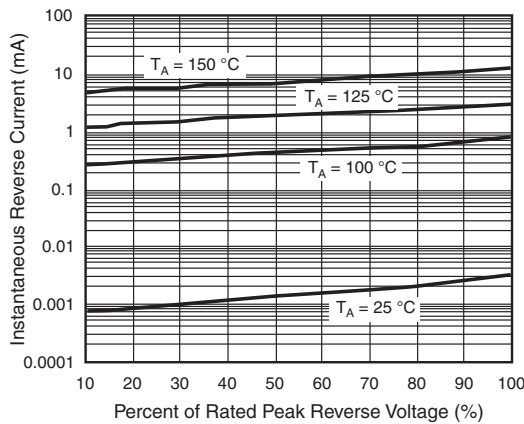
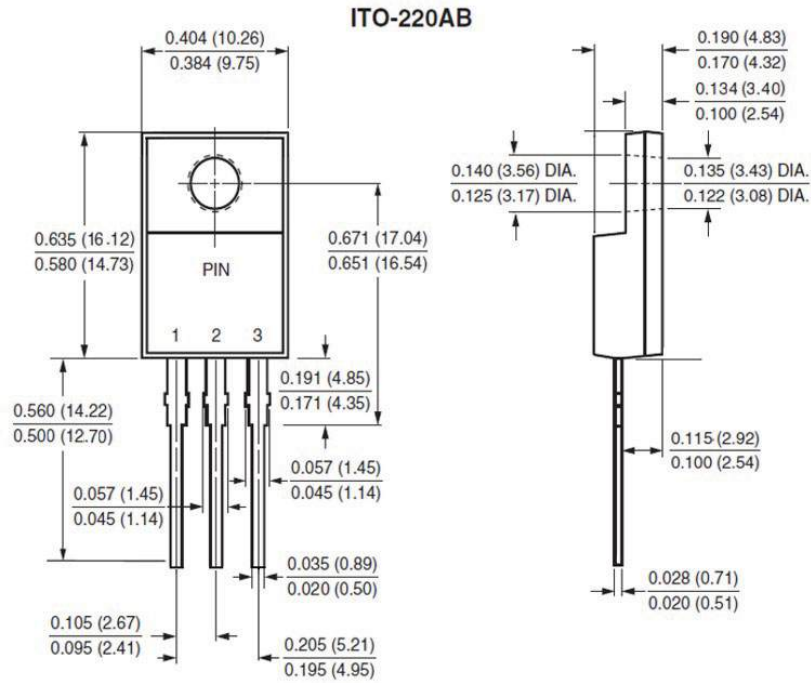


Fig. 5 - Typical Reverse Characteristics Per Diode



## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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